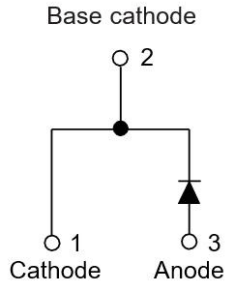
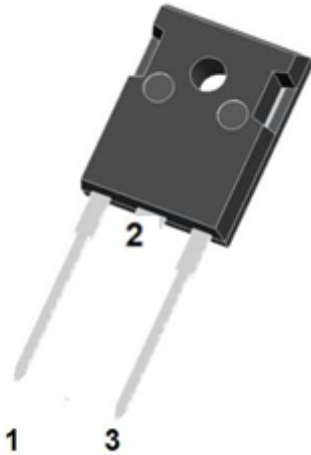


Ultra-Fast Recovery Diodes 30A FRED



Features

- Adopt FRED chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

Typical Applications

- Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-247AC
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■ Maximum Ratings (T_j=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MURU3060P
Device marking code			MURU3060P
Repetitive Peak Reverse Voltage	VRRM	V	600
Average Rectified Output Current @60Hz sine wave, R-load, T _c (FIG.1)	I _O	A	30
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _j =25°C	I _{FSM}	A	460
Current Squared Time @1ms≤t≤8.3ms T _j =25°C,	I ² t	A ² s	878
Storage Temperature	T _{stg}	°C	-55 ~ +175
Junction Temperature	T _j	°C	-55 ~ +175
Typical Junction capacitance @4V,1MHz	C _j	pF	135



MURU3060P

■ Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Typ	Max
Instantaneous forward voltage drop per diode	V_{FM}	V	$I_{FM}=30.0A$ @ $T_J=25^{\circ}C$	-	1.37	1.55
			$I_{FM}=30.0A$ @ $T_J=125^{\circ}C$	-	1.18	1.35
DC reverse current at rated DC blocking voltage per diode	I_{RRM1}	uA	$V_{RM}=V_{RRM}$ $T_J=25^{\circ}C$	-	-	5.0
	I_{RRM2}		$V_{RM}=V_{RRM}$ $T_J=125^{\circ}C$	-	-	200
Reverse Recovery Time	T_{rr}	ns	$I_F=0.5A$ $I_{RM}=1A$ $I_{RR}=0.25A$ $T_J=25^{\circ}C$	-	30	45
			$T_J=25^{\circ}C$	-	63	-
			$T_J=125^{\circ}C$	-	100	-
Peak recovery current	I_{RRM}	A	$T_J=25^{\circ}C$	-	4.67	-
			$T_J=125^{\circ}C$			
Reverse recovery charge	Q_{rr}	nC	$T_J=25^{\circ}C$	-	148	-
			$T_J=125^{\circ}C$	-	640	-

■ Thermal Characteristics ($T_J=25^{\circ}C$ Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MURU3060P
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	$^{\circ}C/W$	1.0
	Between junction and Air	$R_{\theta J-A}$	$^{\circ}C/W$	40

■ Characteristics(Typical)

FIG1: I_o - T_c Curve

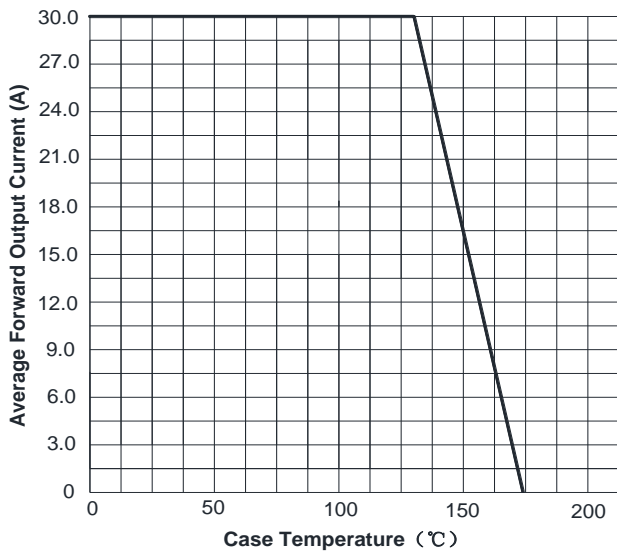


FIG2: Surge Forward Current Capability

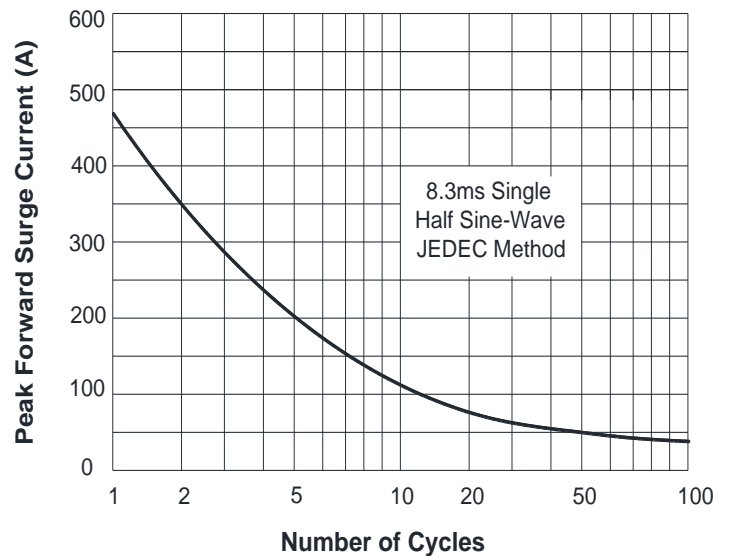


FIG3: Forward Voltage

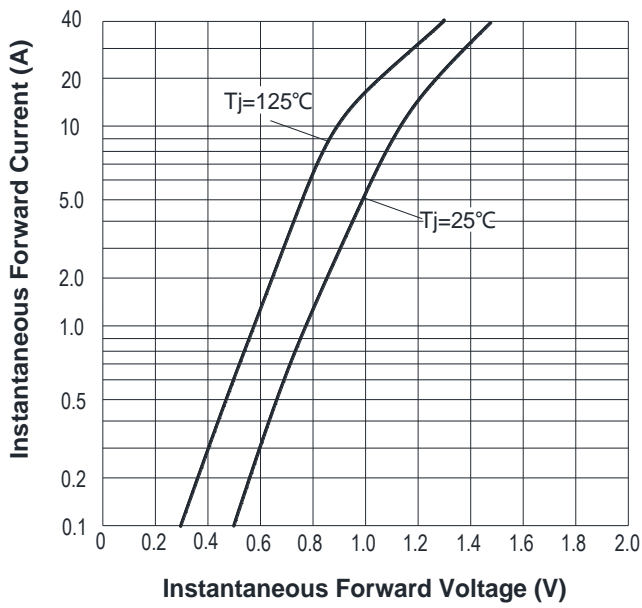


FIG.4: Instantaneous Reverse Characteristics

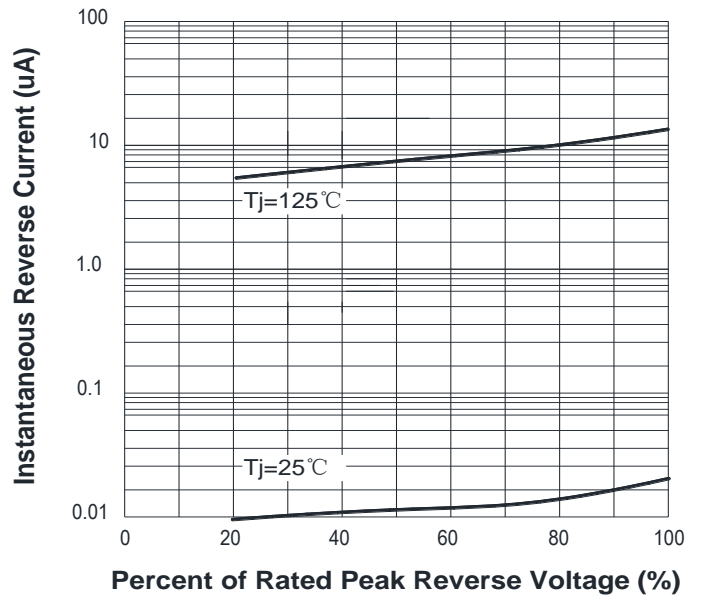
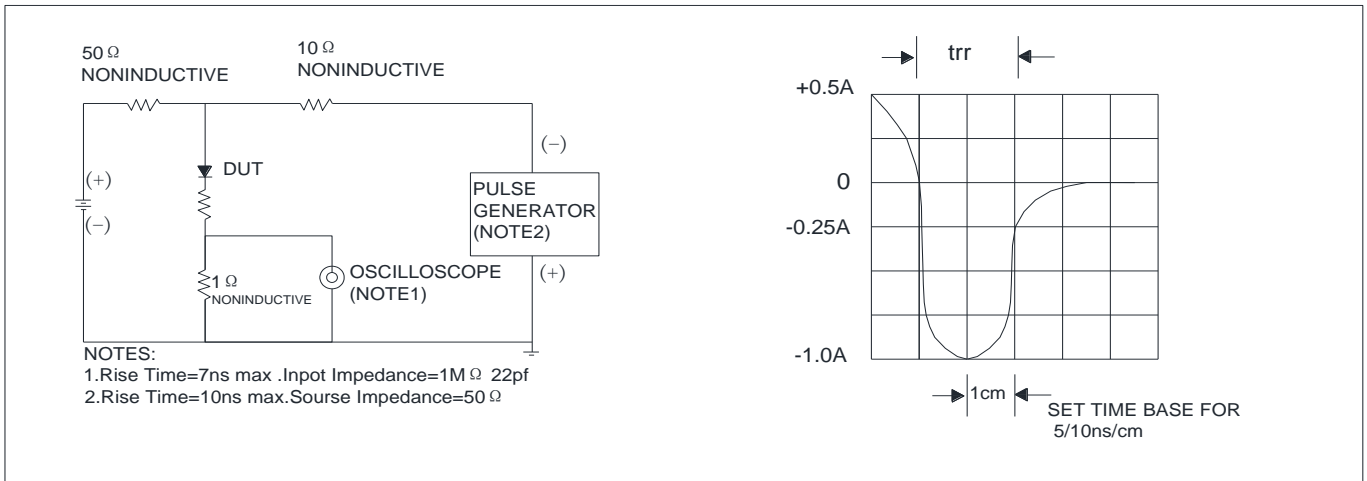


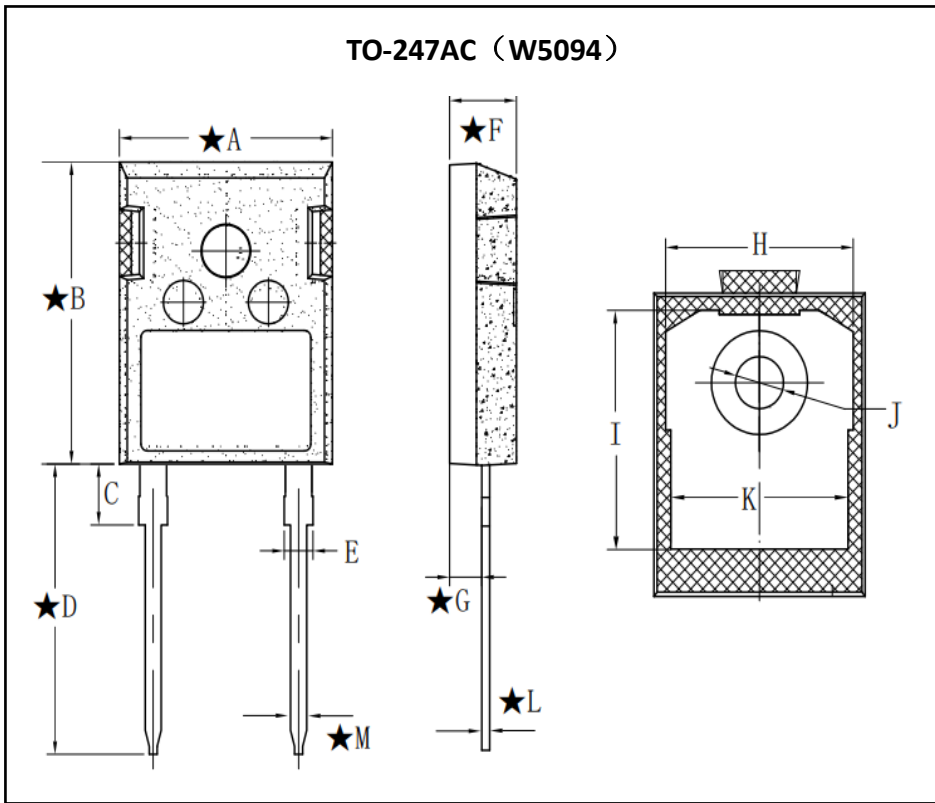
FIG.5: Diagram of circuit and Testing wave form of reverse recovery time





MURU3060P

■ Outline Dimensions



TO-247AC		
Dim	Min	Max
A	15.72	16.12
B	20.7	21.1
C	4.02	4.42
D	19.9	20.3
E	2.0	2.3
F	4.8	5.2
G	2.3	2.5
H	TYP 14.02	
I	TYP 16.55	
J	3.5	3.7
K	TYP 13.26	
L	0.58	0.62
M	1.15	1.25



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